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U.S. Department of Commerce Patent and Trademark Office		APPLICANT KUSUNOKI ET AL.	
Information Disclosure Statement by Applicant		FILING DATE December 1, 2003	GROUP 2828

U.S. Patent Documents

Foreign Patent Documents

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

hp	Yokoo, Kuniyoshi, et al., "Emission characteristics of metal-oxide-semiconductor electron tunneling cathode", J. Vac. Sci. Technol. B 11(2), American Vacuum Society, March/April 1993 PP429-432
hp	Negishi, Nobuyasu, et al, "High Efficiency Electron-Emission in PVSiO/Si/Al Structure", Japan Appl. Phys. Vol. 36, 1997, PP 939-941
hp	Okamoto, Shinji "Electronic discharge from EL thin film - Thin film cold cathode", NHK Science and Technical Research Laboratories", 1994, PP 592-595 (with English translation PP 1-4)
hp	Koshida, Nobuyoshi, "Luminescence of Porous Silicon Indirectly and directly exceeding the frame of the transition", Department of Electronic and Information Engineering, Faculty of Technology, Tokyo University of Agriculture and Technology, 1997 PP 437-443, (with English translation PP 1-10)
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EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP 609; draw a line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant